

LM118QML Operational Amplifier

Check for Samples: LM118QML

FEATURES

- 15 MHz Small Signal Bandwidth
- Ensured 50V/µs Slew Rate
- Maximum Bias Current of 250 nA
- Operates from Supplies of ±5V to ±20V
- **Internal Frequency Compensation**
- Input and Output Overload Protected
- Pin Compatible with General Purpose Op **Amps**

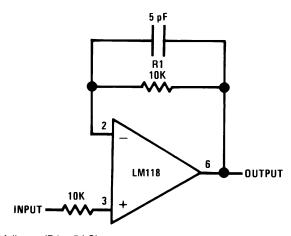
DESCRIPTION

The LM118 is a precision high speed operational amplifier designed for applications requiring wide bandwidth and high slew rate. It features a factor of ten increase in speed over general purpose devices without sacrificing DC performance.

The LM118 has internal unity gain frequency compensation. This considerably simplifies application since no external components are necessary for operation. However, unlike most internally compensated amplifiers, external frequency compensation may added for be performance. For inverting applications, feed forward compensation will boost the slew rate to over 150V/us and almost double the bandwidth. Overcompensation can be used with the amplifier for greater stability when maximum bandwidth is not needed. Further, a single capacitor can be added to reduce the 0.1% settling time to under 1 µs.

The high speed and fast settling time of this op amp makes it useful in A/D converters, oscillators, active filters, sample and hold circuits, or general purpose amplifiers. This device is easy to apply and offers an order of magnitude better AC performance than industry standards such as the LM709.

Fast Voltage Follower



Do not hard-wire as voltage follower (R1 \geq 5 k Ω)

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Connection Diagram

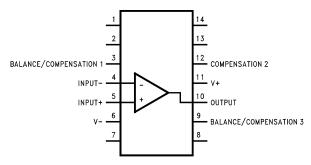


Figure 1. CDIP Package Top View See Package Number J0014A

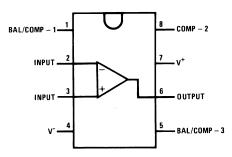


Figure 3. CDIP Package Top View See Package Number NAB0008A

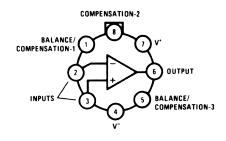
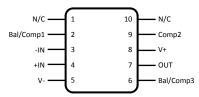


Figure 2. TO-99 Top View See Package Number LMC



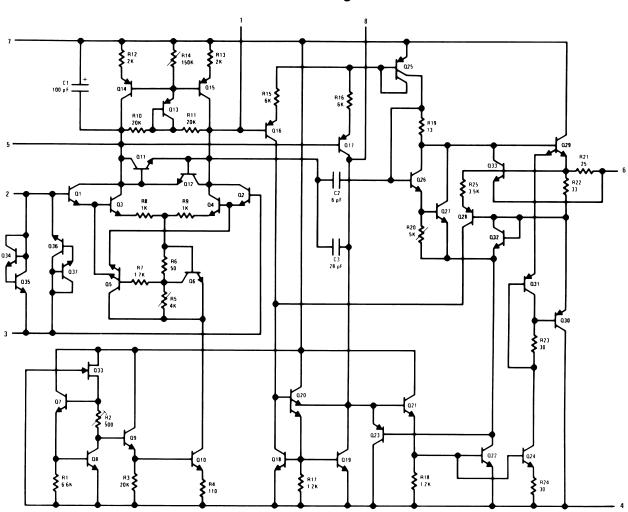
Pin connections shown on schematic diagram and typical applications are for TO package.

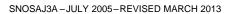
Figure 4. CLGA Package Top View See NS Package Number NAC0010A

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Schematic Diagram







Absolute Maximum Ratings(1)

Supply Voltage			±20V		
117	8 LD TO-99		750mW		
(2)	8LD CDIP	CDIP			
Power Dissipation (2)	14LD CDIP		1250mW		
	10LD CLGA		600mW		
Differential Input Current ⁽³⁾			±10 mA		
Input Voltage (4)			±15V		
Output Short-Circuit Duration			Continuous		
Operating Temperature Range			-55°C ≤ T _A ≤ +125°C		
Thermal Resistance		8 LD TO-99 (Still Air @ 0.5W)	160°C/W		
		8 LD TO-99 (500LF / Min Air flow @ 0.5W)	86°C/W		
		8LD CDIP (Still Air @ 0.5W)	120°C/W		
		8LD CDIP (500LF / Min Air flow @ 0.5W)	66°C/W		
	θ_{JA}	14LD CDIP (Still Air @ 0.5W)	87°C/W		
		14LD CDIP (500LF / Min Air flow @ 0.5W)	51°C/W		
		10LD CLGA (Still Air @ 0.5W)	198°C/W		
		10LD CLGA (500LF / Min Air flow @ 0.5W)	124°C/W		
		8 LD TO-99	48°C/W		
	0	8LD CDIP	17°C/W		
	θ_{JC}	14LD CDIP	17°C/W		
		10LD CLGA	22°C/W		
Storage Temperature Range			-65°C ≤ T _A ≤ +150°C		
Lead Temperature (Soldering, 1	0 seconds)		300°C		
ESD Tolerance ⁽⁵⁾			2000V		

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not ensure specific performance limits. For specifications and test conditions, see the Electrical Characteristics. The specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
- (2) The maximum power dissipation must be derated at elevated temperatures and is dictated by T_{Jmax} (maximum junction temperature), θ_{JA} (package junction to ambient thermal resistance), and T_A (ambient temperature). The maximum allowable power dissipation at any temperature is P_{Dmax} = (T_{Imax} T_A)/θ_{JA} or the number given in the Absolute Maximum Ratings, whichever is lower.
- temperature is P_{Dmax} = (T_{Jmax} T_A)/θ_{JA} or the number given in the Absolute Maximum Ratings, whichever is lower.

 (3) The inputs are shunted with back-to-back diodes for over voltage protection. Therefore, excessive current will flow if a differential input voltage in excess of 1V is applied between the inputs unless some limiting resistance is used.
- (4) For supply voltages less than ±15V, the absolute maximum input voltage is equal to the supply voltage.
- (5) Human body model, $1.5 \text{ k}\Omega$ in series with 100 pF.



Quality Conformance Inspection

Mil-Std-883, Method 5005; Group A

Subgroup	Description	Temp°C
1	Static tests at	25
2	Static tests at	125
3	Static tests at	-55
4	Dynamic tests at	25
5	Dynamic tests at	125
6	Dynamic tests at	-55
7	Functional tests at	25
8A	Functional tests at	125
8B	Functional tests at	-55
9	Switching tests at	25
10	Switching tests at	125
11	Switching tests at	-55
12	Settling time at	25
13	Settling time at	125
14	Settling time at	-55

LM118/883 Electrical Characteristics DC Parameters

The following conditions apply, unless otherwise specified.

DC $V_{CC} = \pm 15V$, $V_{CM} = 0V$

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub- groups
V _{IO}	Input Offset Voltage	$V_{CM} = \pm 11.5V, R_S = 50\Omega$		-4.0	+4.0	mV	1
				-6.0	+6.0	mV	2, 3
		$V_{CC} = \pm 20V, R_S = 50\Omega$		-4.0	+4.0	mV	1
			-4.0 +4.0 -6.0 +6.0 -4.0 +4.0 -6.0 +6.0 -4.0 +4.0 -6.0 +6.0 -4.0 +4.0 -6.0 +6.0 -4.0 +4.0 -6.0 +6.0 -50 +50 -100 +100 -50 +50 -100 +100 -50 +50 -100 +100 1.0 250 1.0 500 1.0 500 1.0 500 70	mV	2, 3		
l _{IO} Ir		$V_{CC} = \pm 20V, V_{CM} = \pm 15V,$		-4.0	+4.0	mV	1
		$R_S = 50\Omega$		-6.0	+6.0	mV	2, 3
		$V_{CC} = \pm 5V$, $R_S = 50\Omega$		-4.0	+4.0	mV	1
				-6.0	+6.0	mV	2, 3
I _{IO}	Input Offset Current	$V_{CM} = \pm 11.5V, R_S = 10K\Omega$	Notes Min Max Unit gr -4.0	1			
I _{IB} I				-100	+100	nA	2, 3
		$V_{CC} = \pm 20V$, $R_S = 10K\Omega$		-50	+50	nA	1
				-100	+100	nA	2, 3
		$V_{CC} = \pm 5V$, $R_S = 10K\Omega$		-50	+50	nA	1
				-100	-4.0 +4.0 mV -6.0 +6.0 mV -50 +50 nA -100 +100 nA -50 +50 nA -100 +100 nA -50 +50 nA -100 +100 nA -50 +50 nA -100 500 nA 1.0 250 nA 1.0 500 nA	2, 3	
I _{IB}	Input Bias Current	$V_{CM} = \pm 11.5V, R_{S} = 10K\Omega$		1.0	250	### Hand State of the control of the	1
		$\begin{array}{c} -6.0 \\ V_{CC} = \pm 20 \text{V}, R_S = 50 \Omega \\ \hline \\ V_{CC} = \pm 20 \text{V}, V_{CM} = \pm 15 \text{V}, \\ R_S = 50 \Omega \\ \hline \\ V_{CC} = \pm 5 \text{V}, R_S = 50 \Omega \\ \hline \\ V_{CC} = \pm 5 \text{V}, R_S = 50 \Omega \\ \hline \\ V_{CM} = \pm 11.5 \text{V}, R_S = 10 \text{K} \Omega \\ \hline \\ V_{CC} = \pm 20 \text{V}, R_S = 10 \text{K} \Omega \\ \hline \\ V_{CC} = \pm 20 \text{V}, R_S = 10 \text{K} \Omega \\ \hline \\ V_{CC} = \pm 5 \text{V}, R_S = 10 \text{K} \Omega \\ \hline \\ V_{CC} = \pm 5 \text{V}, R_S = 10 \text{K} \Omega \\ \hline \\ V_{CC} = \pm 20 \text{V}, R_S = 10 \text{K} \Omega \\ \hline \\ V_{CC} = \pm 20 \text{V}, R_S = 10 \text{K} \Omega \\ \hline \\ V_{CC} = \pm 20 \text{V}, R_S = 10 \text{K} \Omega \\ \hline \\ V_{CC} = \pm 20 \text{V}, R_S = 10 \text{K} \Omega \\ \hline \\ V_{CC} = \pm 20 \text{V}, R_S = 10 \text{K} \Omega \\ \hline \\ V_{CC} = \pm 20 \text{V}, R_S = 10 \text{K} \Omega \\ \hline \\ V_{CC} = \pm 20 \text{V}, R_S = 50 \Omega \\ \hline \\ V_{CC} = \pm 20 \text{V}, R_S = 50 \Omega \\ \hline \\ V_{CC} = \pm 20 \text{V}, R_S = 50 \Omega \\ \hline \\ V_{CC} = \pm 15 \text{V}, V_{CM} = \pm 11.5 \text{V}, R_S = 50 \Omega \\ \hline \\ V_{CC} = \pm 15 \text{V}, V_{CM} = \pm 11.5 \text{V}, R_S = 50 \Omega \\ \hline \end{array}$	500	nA	2, 3		
			1.0	250	nA	1	
I _{IB}				1.0	500	nA	2, 3
		$V_{CC} = \pm 5V$, $R_S = 10K\Omega$		1.0	250	nA	1
				1.0	500	nA	2, 3
PSRR	Power Supply Rejection Ratio	$+V_{CC} = 20V \text{ to 5V}, R_S = 50\Omega$	$R_S = 50\Omega$ 70		dB	1, 2, 3	
		$-V_{CC} = -20V \text{ to } -5V, R_S = 50\Omega$		70		dB	1, 2, 3
CMRR	Common Mode Rejection Ratio	$V_{CC} = \pm 15V, V_{CM} = \pm 11.5V, R_{S} =$		80		dB	1, 2, 3
+l _{OS}	Short Circuit Current	t < 25mS		-65	-5.0	mA	1, 2, 3

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LM118/883 Electrical Characteristics DC Parameters (continued)

The following conditions apply, unless otherwise specified.

DC $V_{CC} = \pm 15V$, $V_{CM} = 0V$

Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub- groups
-l _{OS}	Short Circuit Current	t < 25mS		5.0	65	mA	1, 2
				5.0	80	mA	3
I _{CC}	Power Supply Current	$V_{CC} = \pm 20V$			8.0	mA	1
V _{IO} adi					7.0	mA	2
					11	mA	3
V _{IO} adj.	Input Offset Voltage Adjust	V _{CC} = ± 20V		4.0	-4.0	mV	1
R _I	Input Resistance		See ⁽¹⁾	1.0		МΩ	1
V _I	Input Voltage Range	V _{CC} = ± 15V	See ⁽²⁾	-11.5	+11. 5	V	1, 2, 3
A _{VS}	Large Signal Voltage Gain	$R_L = 2K\Omega$, $V_O = 0$ to -10V	See (3)	50		V/mV	2 3 1
			See ⁽³⁾	25		V/mV	5, 6
		$R_L = 2K\Omega$, $V_O = 0$ to +10V	See ⁽³⁾	50		V/mV	4
			See ⁽³⁾	25		V/mV	5, 6
Vo	Output Voltage Swing	$R_L = 2K\Omega$		+12	-12	V	4, 5, 6

⁽¹⁾ Specified by design not tested(2) Specified by CMRR

LM118/883 Electrical Characteristics AC Parameters

The following conditions apply parameters, unless otherwise specified.

AC $V_{CC} = \pm 15V$, $V_{CM} = 0V$, $R_S = 0\Omega$, $R_L = 2K\Omega$,, $C_L = 33pF$

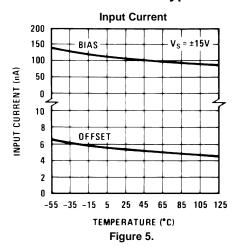
Symbol	Parameter	Conditions	Notes	Min	Max	Unit	Sub- groups
S _R	Slew Rate	$V_{CC} = \pm 20V$, $V_I = -5V$ to +5V, $A_V = 1$		50		V/µS	7
		$V_{CC} = \pm 20V$, $V_I = +5V$ to -5V, $A_V = 1$		50		V/µS	7

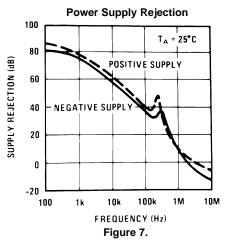
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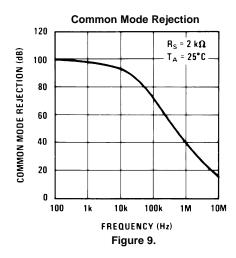
Datalog in K = V/mV

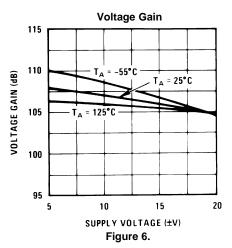


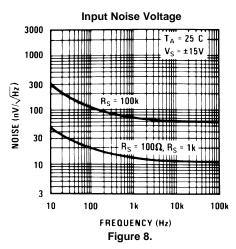
Typical Performance Characteristics

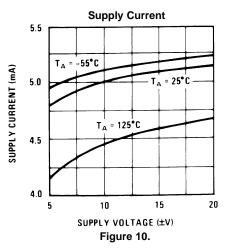






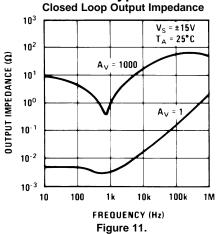


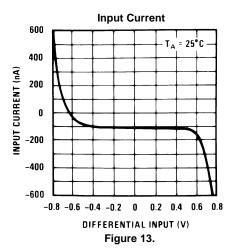


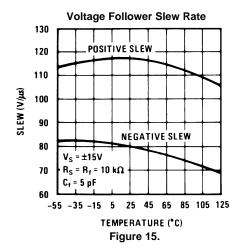


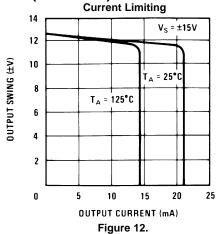


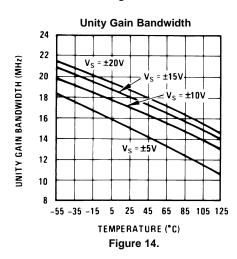
Typical Performance Characteristics (continued)

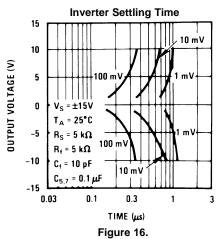






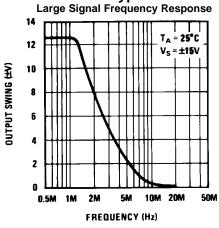




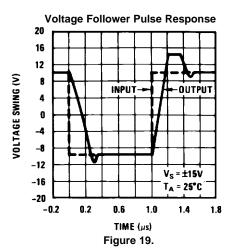




Typical Performance Characteristics (continued)







120 $V_S = \pm 15V$ $T_A = 25^{\circ}C$ 225

Open Loop Frequency Response

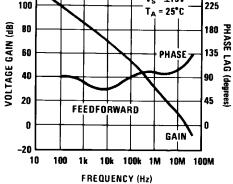


Figure 21.

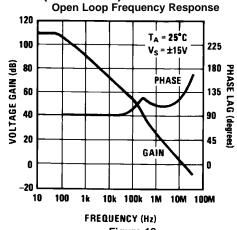


Figure 18.

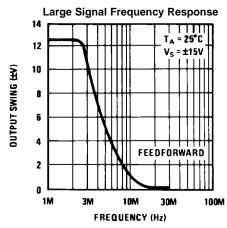
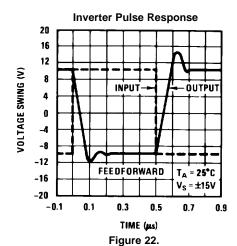


Figure 20.

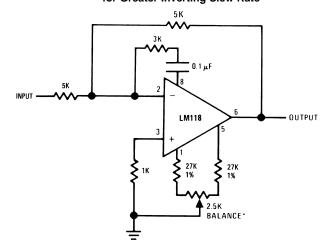


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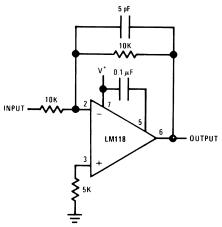


AUXILIARY CIRCUITS

Feedforward Compensation for Greater Inverting Slew Rate



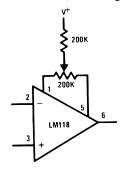
Compensation for Minimum Settling Time



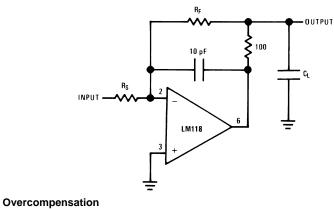
Slew and settling time to 0.1% for a 10V step change is 800 ns.

Slew rate typically 150V/µs.

Offset Balancing



Isolating Large Capacitive Loads



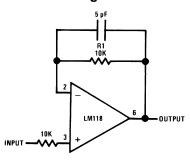
LM118 6

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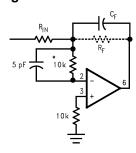
Typical Applications

Fast Voltage Follower



Do not hard-wire as voltage follower (R1 \geq 5 k Ω)

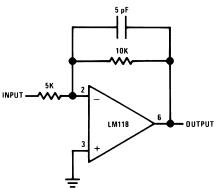
Integrator or Slow Inverter



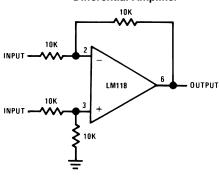
 $C_F = Large (C_F \ge 50 pF)$

*Do not hard-wire as integrator or slow inverter; insert a 10k-5 pF network in series with the input, to prevent oscillation.



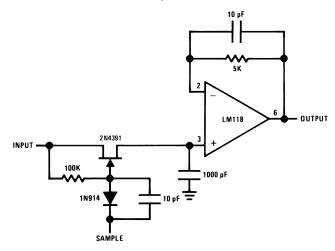


Differential Amplifier

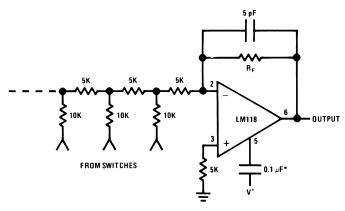




Fast Sample and Hold



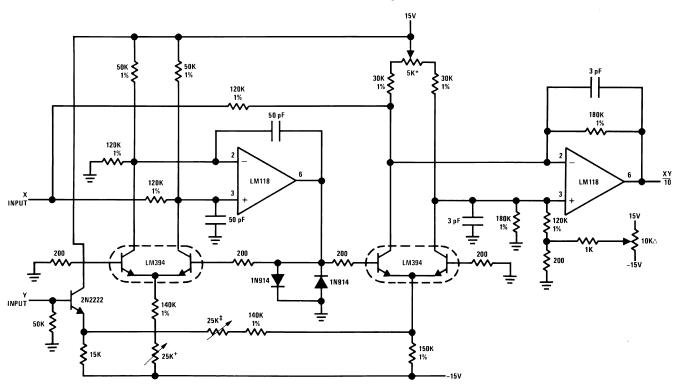
D/A Converter Using Ladder Network



*Optional—Reduces settling time.



Four Quadrant Multiplier



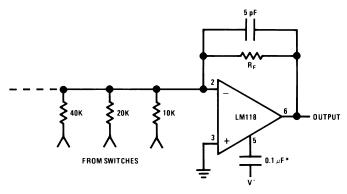
ΔOutput zero.

*"Y" zero

+"X" zero

‡Full scale adjust.

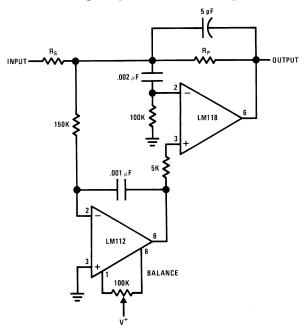
D/A Converter Using Binary Weighted Network



*Optional—Reduces settling time.



Fast Summing Amplifier with Low Input Current



*L1-10V-14 mA bulb ELDEMA 1869

R1 = R2

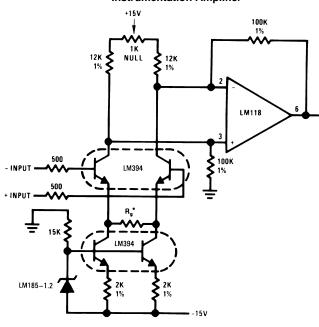
C1 = C2

 $f = \frac{1}{2\pi R2 C1}$

Wein Bridge Sine Wave Oscillator

2 LM118 6 OUTPUT 3 R3 1000 pF 20K 1%

Instrumentation Amplifier



*Gain $\geq \frac{200 \text{K}}{\text{R}_g}$ for 1.5K $\leq \text{R}_g \leq 200 \text{K}$



REVISION HISTORY SECTION

Date Released	Revision	Section	Originator	Changes
07/12/05	А	New Release, Corporate format	L. Lytle	1 MDS data sheet, MNLM118–X Rev 0A0 was converted into the Corp. datasheet format. MDS datasheet will be archived.
03/20/2013	А	All Sections		Changed Layout of National Data Sheet to TI format

Product Folder Links: LM118QML

www.ti.com 11-Nov-2025

PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking
	(1)	(2)			(3)	(4)	(5)		(6)
LM118 MD8	Active	Production	DIESALE (Y) 0	182 JEDEC TRAY (5+1)	Yes	Call TI	Level-1-NA-UNLIM	-55 to 125	
LM118H/883	Active	Production	TO-99 (LMC) 8	20 JEDEC TRAY (5+1)	Yes	Call TI	Level-1-NA-UNLIM	-55 to 125	LM118H/883 Q ACO LM118H/883 Q >T
LM118J-8/883	Active	Production	CDIP (NAB) 8	40 TUBE	No	SNPB	Level-1-NA-UNLIM	-55 to 125	LM118J-8 /883 Q ACO /883 Q >T

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

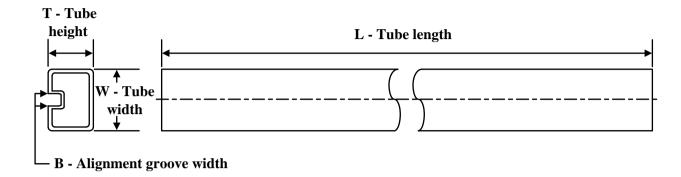
⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

PACKAGE MATERIALS INFORMATION

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TUBE



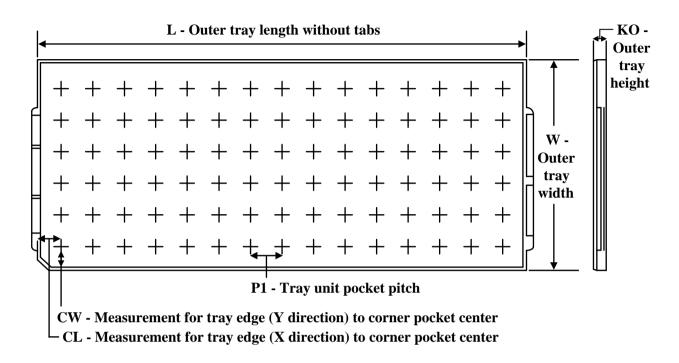
*All dimensions are nominal

Device	Package Name	Package Type Pins		SPQ	L (mm)	W (mm)	T (µm)	B (mm)	
LM118J-8/883	NAB	CDIP	8	40	506.98	15.24	13440	NA	



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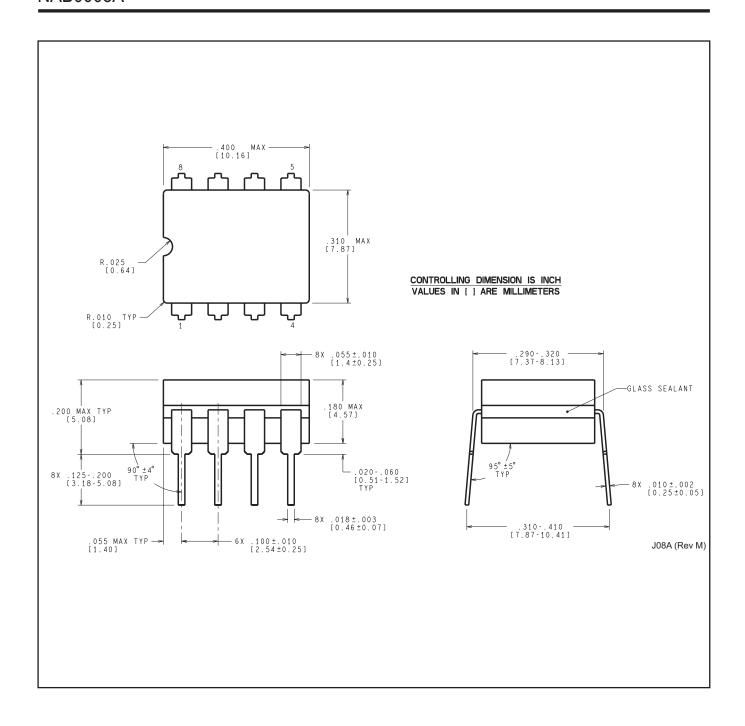
TRAY



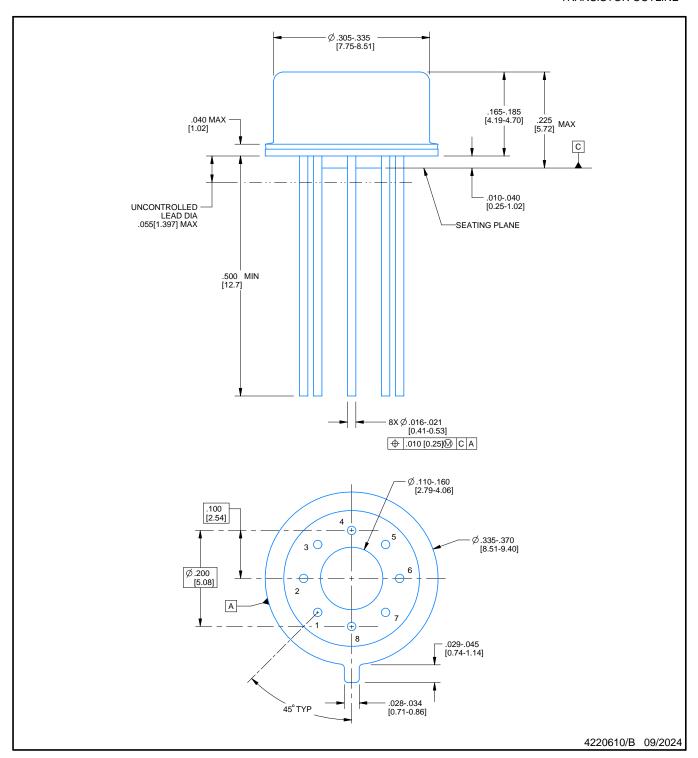
Chamfer on Tray corner indicates Pin 1 orientation of packed units.

*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	Unit array matrix	Max temperature (°C)	L (mm)	W (mm)	Κ0 (μm)	P1 (mm)	CL (mm)	CW (mm)
LM118H/883	LMC	TO-CAN	8	20	2 X 10	150	126.49	61.98	8890	11.18	12.95	18.54



TRANSISTOR OUTLINE



NOTES:

- 1. All linear dimensions are in inches [millimeters]. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

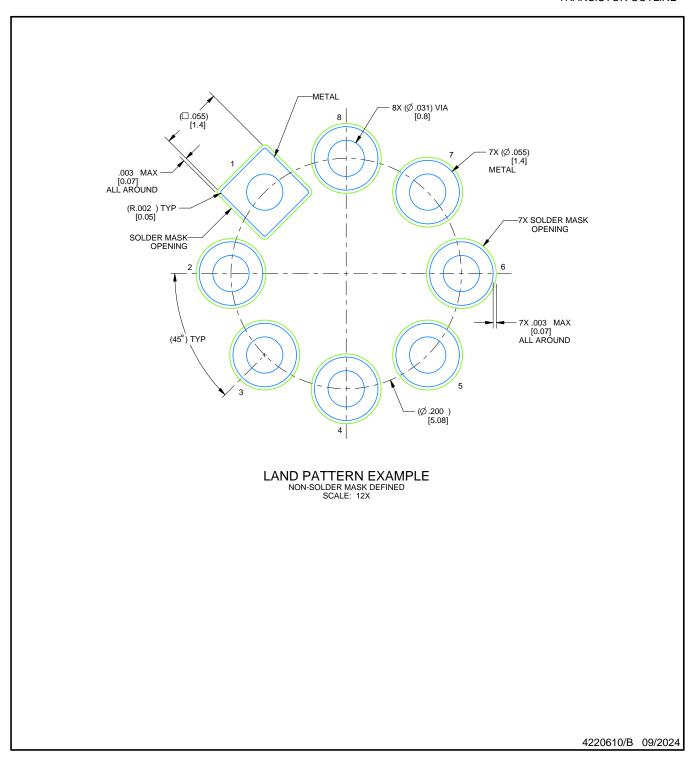
 2. This drawing is subject to change without notice.

 3. Pin numbers shown for reference only. Numbers may not be marked on package.

- 4. Reference JEDEC registration MO-002/TO-99.



TRANSISTOR OUTLINE



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